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Supporting Information

Single-Composition White-Emitting $NaSrBO_3:Ce^{3+}$, Sm^{3+}, Tb^{3+} Phosphors for NUV Light-Emitting Diodes

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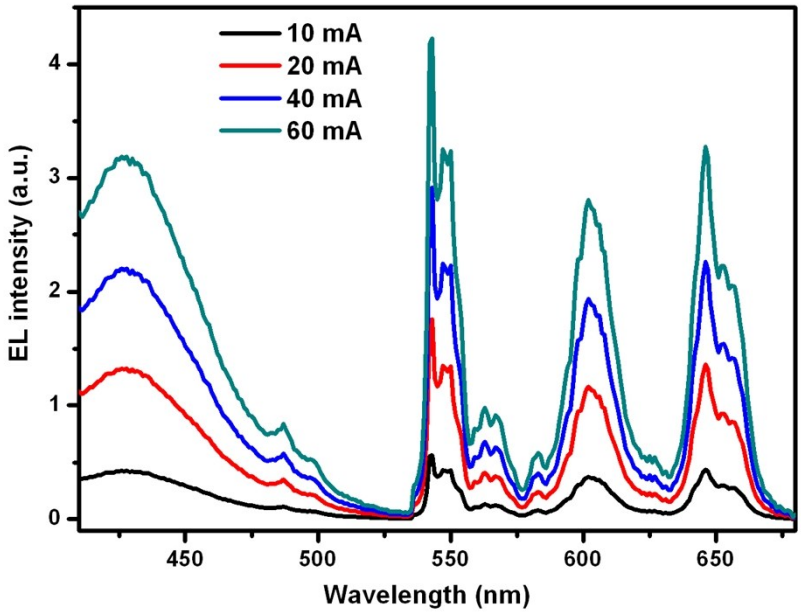

Fig. S1 Electroluminescence (EL) spectra of the fabricated white light emitting diodes (WLED) device under various drive currents. The fabricated WLED device were operated at 3.0 V with various drive currents of 10, 20, 40 and 60 mA, respectively. The EL intensity increases with the increased driven current, whereas the EL pattern remains essentially unchanged.

Table S1 Photoelectric parameters for the fabricated WLED device under various drive currents. With the increased drive current, the correlated color temperature (CCT) increases slightly from 6731 to 7062 K while the color rendering index (Ra) remains around 80. The slight variation of the chromaticity coordinate, merely 0.006 for CIE-x and 0.004 for CIE-y, respectively, confirms the negligible color fluctuation in the device.

Current (mA)	CCT (K)	Chromaticity coordinate		Ra
		x	y	
10	6731	0.311	0.314	80.1
20	6780	0.309	0.311	80.0
40	6993	0.306	0.310	79.5
60	7062	0.305	0.310	79.5